

A5970D

Up to 1 A step down switching regulator for automotive applications

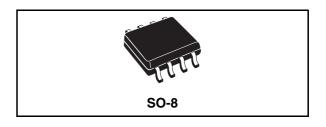
Features

- Qualified following the AEC-Q100 requirements (temperature grade 3), see PPAP for more details.
- Up to 1 A DC output current
- Operating input voltage from 4 V to 36 V
- Output voltage adjustable from 1.235 V to 35 V
- Low dropout operation: 100 % duty cycle
- 250 kHz Internally fixed frequency
- Voltage feedforward
- Zero load current operation
- Internal current limiting
- Inhibit for zero current consumption
- Synchronization
- Protection against feedback disconnection
- Thermal shutdown

Applications

Dedicated to automotive applications

Figure 1. Application schematic



Description

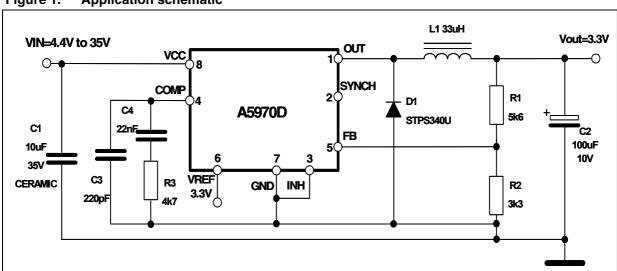
The A5970D is a step down monolithic power switching regulator capable to deliver up to 1 A at output voltages from 1.2 V to 35 V.

The device uses an internal P-channel D-MOS transistor (with a typical $R_{DS(on)}$ of 250 m Ω) as switching element to minimize the size of the external components.

An internal oscillator fixes the switching frequency at 250 kHz.

Having a minimum input voltage of 4 V only, it is particularly suitable for 5 V bus.

Pulse by pulse current limit with the internal frequency modulation offers an effective constant current short circuit protection.



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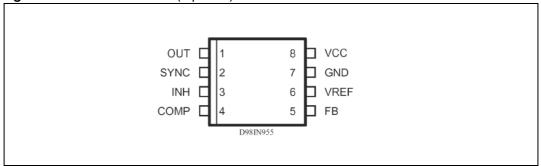
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1 Pin settings

1.1 Pin connection

Figure 1. Pin connection (top view)



1.2 Pin description

Table 1. Pin description

N	Pin	Description		
1	OUT	Regulator output.		
2	SYNCH	Master/slave synchronization.		
3	INH	A logical signal (active high) disables the device. If INH not used the pin must be grounded. When it is open an internal pull-up disable the device.		
4	COMP	E/A output for frequency compensation.		
5	FB	Feedback input. Connecting directly to this pin results in an output voltage of 1.23 V. An extenal resistive divider is required for higher output voltages.		
6	VREF	3.3 V VREF. No cap is requested for stability.		
7	GND	Ground.		
8	VCC	Unregulated DC input voltage.		

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2 Electrical data

2.1 Maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V ₈	Input voltage	40	V
V ₁	OUT pin DC voltage OUT pin peak voltage at $\Delta t = 0.1 \mu s$	-1 to 40 -5 to 40	V V
I ₁	Maximum output current	int. limit.	
V ₄ , V ₅	Analog pins	4	V
V ₃	INH	-0.3 to V _{CC}	V
V ₂	SYNCH	-0.3 to 4	V
P _{TOT}	Power dissipation at T _A ≤ 70 °C	0.75	W
Tj	Operating junction temperature range	-40 to 150	°C
T _{STG}	Storage temperature range	-55 to 150	°C

2.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	SO8	Unit
R_{thJA}	Maximum thermal resistance junction-ambient	120 ⁽¹⁾	°C/W

^{1.} Package mounted on board

3 Electrical characteristics

Table 4. Electrical characteristics

 $(T_J = -40 \text{ to } 125 \,^{\circ}\text{C}, \, V_{CC} = 12 \,\text{V}, \, \text{unless otherwise specified})$

Symbol	Parameter	Test condition	Min	Тур	Max	Unit
V _{CC}	Operating input voltage range	V ₀ = 1.235 V; I ₀ = 1 A	4		36	V
R _{DS(on)}	MOSFET on resistance			0.250	0.5	Ω
_	Maximum limiting	V _{CC} = 5 V	1.35	1.87	2.25	^
ΙL	current (1)	V _{CC} = 5 V, T _J = 25 °C	1.5	1.87	2.25	Α
f _{SW}	Switching frequency		212	250	280	kHz
	Duty cycle		0		100	%
Dynamic o	characteristics (see test	circuit).				
V ₅	Voltage feedback	4.4 V < V _{CC} < 36 V, 20 mA < I ₀ < 2 A	1.198	1.235	1.272	V
η	Efficiency	$V_0 = 5 \text{ V}, V_{CC} = 12 \text{ V}$		90		%
DC charac	teristics					
I _{qop}	Total operating quiescent current			3	5	mA
Iq	Quiescent current	Duty cycle=0; V _{FB} =1.5 V			2.5	mA
	Total stand-by quiescent current	V _{inh} > 2.2 V		50	100	μΑ
I _{qst-by}		V _{CC} = 36 V; V _{inh} > 2.2 V		80	150	μΑ
Inhibit	•					
	INII Laboro de al al contra con	Device ON			0.8	V
	INH threshold voltage	Device OFF	2.2			V
Error amp	lifier			•		
V _{OH}	High level output voltage	V _{FB} = 1 V	3.5			V
V _{OL}	Low level output voltage	V _{FB} = 1.5 V			0.4	V
lo source	Source output current	V _{COMP} = 1.9 V; V _{FB} = 1 V	190	300		μА
lo sink	Sink output current	V _{COMP} = 1.9 V; V _{FB} =1.5 V	1	1.5		mA
lь	Source bias current			2.5	4	μΑ
	DC open loop gain	RL=∞	50	65		dB

Electrical characteristics A5970D

Table 4. Electrical characteristics (continued)

(T_J = -40 to 125 $^{\circ}$ C, V_{CC} =12 V, unless otherwise specified)

Symbol	Parameter	Test condition	Min	Тур	Max	Unit
gm	Transconductance	I _{COMP} = -0.1 mA to 0.1 mA; V _{COMP} = 1.9 V		2.3		mS
Synch fun	ction					
	High input voltage	V _{CC} = 4.4 to 36 V;	2.5		V _{REF}	V
	Low input voltage	V _{CC} = 4.4 to 36 V;			0.74	V
	Slave synch current	V _{synch} = 0.74 V ⁽²⁾ V _{synch} = 2.33 V	0.11 0.21		0.25 0.45	mA
	Master output amplitude	I _{source} = 3 mA	2.75	3		V
	Output pulse width	no load, V _{synch} = 1.65 V	0.20	0.35		μS
Reference	Reference section					
	Reference voltage	I _{REF} = 0 to 5 mA V _{CC} = 4.4 V to 36 V	3.2	3.3	3.399	V
	Line regulation	I _{REF} = 0mA V _{CC} = 4.4 V to 36 V		5	10	mV
	Load regulation	I _{REF} = 0 mA		8	15	mV
	Short circuit current		5	18	35	mA

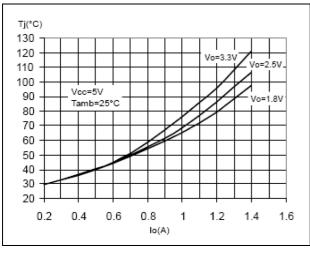
^{1.} With $T_J = 85$ °C, $I_{lim_min} = 1.5$ A, assured by design, characterization and statistical correlation.

^{2.} Guaranteed by design

4 Typical characteristics

Figure 2. Junction temperature vs output current

Figure 3. Load regulation



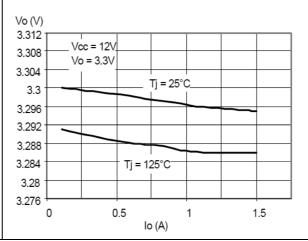
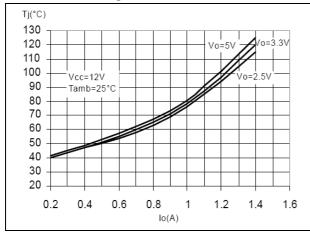


Figure 4. Junction temperature vs output voltage

Figure 5. Line regulation



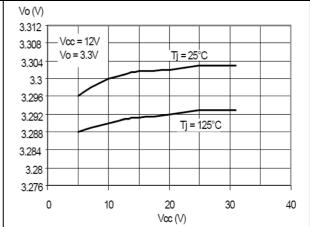


Figure 6. Junction temperature vs output current

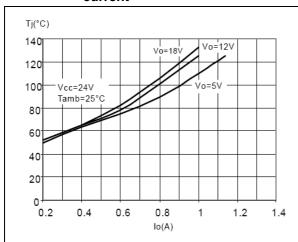


Figure 7. Output voltage vs junction temperature

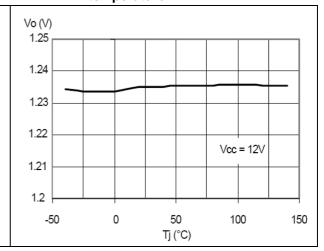


Figure 8. Quiescient current vs junction temperature

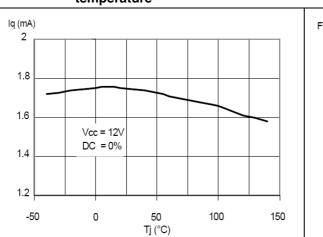
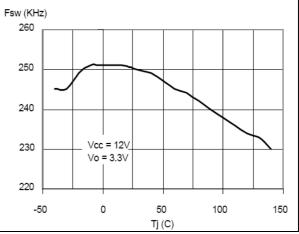


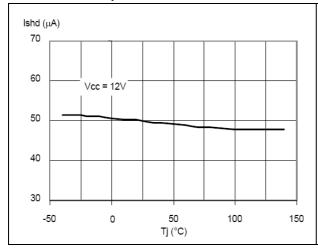
Figure 9. Switching frequency vs junction temperature



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Figure 10. Shutdown current vs junction temperature

Figure 11. Efficiency vs output current



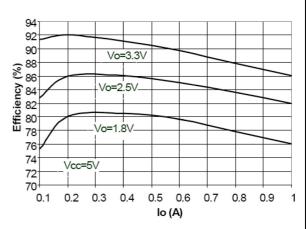
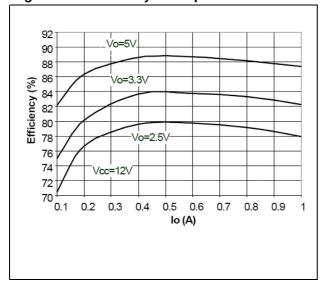


Figure 12. Efficiency vs output current



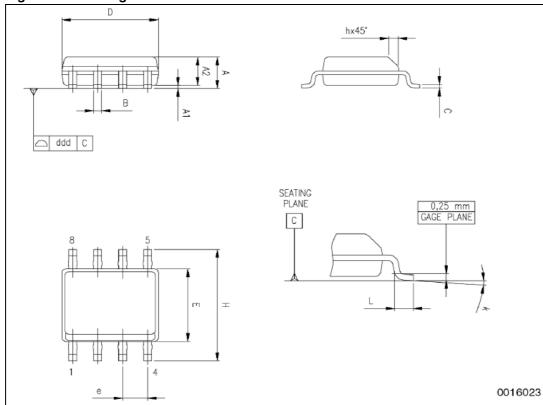
5 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Table 5. SO-8 mechanical data

Dim	mm			inch		
	Min	Тур	Max	Min	Тур	Max
Α	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D ⁽¹⁾	4.80		5.00	0.1890		0.197
E	3.80		4.00	0.15		0.157
е		1.27			0.050	
Н	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k			0° (min),	8° (max)		
ccc			0.10			0.0039

Figure 13. Package dimensions



Revision history A5970D

6 Revision history

Table 6. Document revision history

Date	Revision	Changes		
06-Aug-2007	1	Initial release.		
24-Oct-2007	24-Oct-2007 2 Updated: <i>Table 4 on page 5</i>			
2-May-2008 3		Updated: Cover page, <i>Table 4 on page 5</i>		
27-Aug-2008	4	Updated: Coverpage and Table 4 on page 5		

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